

500.39879X00

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicants: T. KOBAYASHI et al.
Serial No.: 09/811,444
Filed: March 20, 2001
For: NONVOLATILE SEMICONDUCTOR MEMORY DEVICE
WITH IMPROVED GATE OXIDE FILM
ARRANGEMENTS
(As amended)
Group: 2826
Examiner: K. Quinto

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DEC 30 2002

TECHNOLOGY CENTER 2800

AMENDMENT

Assistant Commissioner
for Patents
Washington, D.C. 20231

December 30, 2002

Sir:

In response to the Office Action dated July 31, 2002, the period of response for which extension is requested by the attached Petition for Extension of Time, please amend the above-identified application as follows:

In the Title:*(changed in PALM)*

Please amend the title to read as follows:

-- NONVOLATILE SEMICONDUCTOR MEMOY DEVICE WITH IMPROVED
GATE OXIDE FILM ARRANGEMENTS --

In the Claims:

Please cancel claims 1-6, 8-13 and 15-42 without prejudice.